NSN 5961-00-350-7767

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View Online at https://aerobasegroup.com/nsn/5961-00-350-7767 **Inclosure Material:** Metal **Overall Length:** Between 1.440 inches and 1.525 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** Between 0.865 inches and 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage, dc and 60.0 collector to base voltage, dc and 8.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 15.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 wire hook Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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